NSA5.0AT3G

400 Watt Peak Power Zener Transient Voltage Suppressor

Unidirectional

The NSA5.0AT3G is designed to protect voltage sensitive components from high voltage, high energy transients. It has excellent clamping capability, high surge capability, low zener impedance and a fast response time. The NSA5.0AT3G is ideally suited for use in communication systems, automotive, numerical controls, process controls, medical equipment, business machines, power supplies and many other industrial/consumer applications.

Features

- Peak Power 400 W @ 1 ms
- ESD Rating of Class 3 (> 16 kV) per Human Body Model
- ESD Rating IEC 61000-4-2 (> 30 kV)
- Response Time is Typically < 1 ns
- Flat Handling Surface for Accurate Placement
- Package Design for Top Slide or Bottom Circuit Board Mounting
- Low Profile Package
- Pb-Free Packages are Available

Mechanical Characteristics:

CASE: Void-free, transfer-molded plastic

FINISH: All external surfaces are corrosion resistant and leads are readily solderable

MAXIMUM CASE TEMPERATURE FOR SOLDERING PURPOSES:

260°C for 10 Seconds

POLARITY: Cathode indicated by molded polarity notch or polarity

band

MOUNTING POSITION: Any



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PLASTIC SURFACE MOUNT ZENER OVERVOLTAGE TRANSIENT SUPPRESSOR 400 W PEAK POWER





SMA CASE 403D PLASTIC

MARKING DIAGRAM



QA = Device Code

A = Assembly Location

′ = Year

WW = Work Week

= Pb-Free Package

ORDERING INFORMATION

| Device | Package | Shipping | | |
|------------|------------------|------------------|--|--|
| NSA5.0AT3G | SMA (Pb-Free) | 5000/Tape & Reel | | |

DEVICE MARKING INFORMATION

See specific marking information in the device marking column of the Electrical Characteristics table on page 2 of this data sheet.

MAXIMUM RATINGS

| Rating | Symbol | Value | Unit |
|---|-----------------------------------|-------------------|--------------------|
| Peak Power Dissipation (Note 1) @ T _L = 25°C, Pulse Width = 1 ms | P _{PK} | 400 | W |
| DC Power Dissipation @ T _L = 75°C Measured Zero Lead Length (Note 2) Derate Above 75°C Thermal Resistance from Junction to Lead | P _D | 1.5 20 50 | W mW/°C °C/W |
| DC Power Dissipation (Note 3) @ T _A = 25°C Derate Above 25°C Thermal Resistance from Junction to Ambient | P _D | 0.5 4.0 250 | W mW/°C °C/W |
| Forward Surge Current (Note 4) @ T _A = 25°C | I _{FSM} | 40 | Α |
| Operating and Storage Temperature Range | T _J , T _{stg} | −65 to +150 | °C |

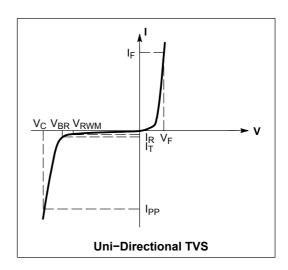
Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

- 1. 10 X 1000 μs, non-repetitive.
- 2. 1" square copper pad, FR-4 board.
- 3. FR-4 board, using Littelfuse minimum recommended footprint, as shown in 403D case outline dimensions spec.
- 4. 1/2 sine wave (or equivalent square wave), PW = 8.3 ms, duty cycle = 4 pulses per minute maximum.

ELECTRICAL CHARACTERISTICS

 $(T_A = 25^{\circ}C \text{ unless otherwise noted})$

| Symbol | Parameter | | | | | |
|-----------------|--|--|--|--|--|--|
| I _{PP} | Maximum Reverse Peak Pulse Current | | | | | |
| V _C | Clamping Voltage @ I _{PP} | | | | | |
| V_{RWM} | Working Peak Reverse Voltage | | | | | |
| I _R | Maximum Reverse Leakage Current @ V _{RWM} | | | | | |
| V_{BR} | Breakdown Voltage @ I _T | | | | | |
| I _T | Test Current | | | | | |
| I _F | Forward Current | | | | | |
| V _F | Forward Voltage @ I _F | | | | | |



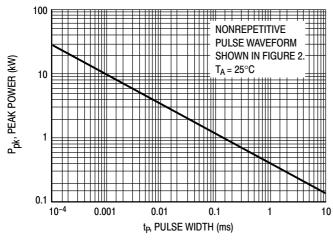
ELECTRICAL CHARACTERISTICS

| | | V _{RWM} I _R @ | | Breakdown Voltage | | | | V _C @ I _{PP} (Note 7) | | С Тур. | V _F @ I _F (Note 9) |
|------------|---------|-----------------------------------|------------------|----------------------------------|-----|------------------|----------------|--|----------|--------|---|
| | Device | (Note 5) | V _{RWM} | V _{BR} (Volts) (Note 6) | | @ I _T | V _C | I _{PP} | (Note 8) | Max | |
| Device | Marking | Volts | μ Α | Min | Nom | Max | mA | Volts | Amps | pF | ٧ |
| NSA5.0AT3G | QA | 5.0 | 400 | 6.4 | 6.7 | 7.0 | 10 | 9.2 | 43.5 | 2450 | 3.5 |

- 5. A transient suppressor is normally selected according to the working peak reverse voltage (V_{RWM}), which should be equal to or greater than the DC or continuous peak operating voltage level.
- 6. V_{BR} measured at pulse test current I_T at an ambient temperature of 25°C.
- 7. Surge current waveform per Figure 2 and derate per Figure 3.
- 8. Bias voltage = 0 V, F = 1.0 MHz, $T_J = 25$ °C.
- 9. 1/2 sine wave or equivalent, PW = 8.3 ms, non-repetitive, I_F = 30 A.

NSA5.0AT3G

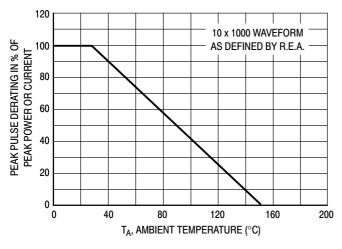
RATING AND TYPICAL CHARACTERISTIC CURVES



120 T_A = 25°C ≤ 10 μs PW (ID) IS DEFINED AS THE ppm, PEAK PULSE CURRENT (%) 100 POINT WHERE THE PEAK CURRENT DECAYS TO 50% OF Ipp. PEAK VALUE -80 Ippm 60 HALF VALUE - Ipp/2 40 10/1000 μs WAVEFORM AS DEFINED BY R.E.A. 20 0 2 3 0 t, TIME (ms)

Figure 1. Pulse Rating Curve

Figure 2. Pulse Waveform



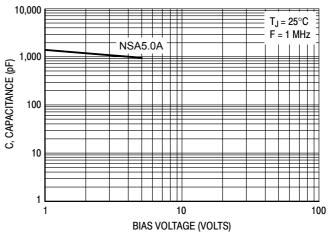


Figure 3. Pulse Derating Curve

Figure 4. Typical Junction Capacitance vs.
Bias Voltage

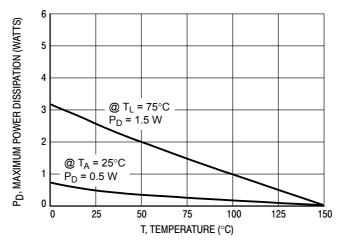
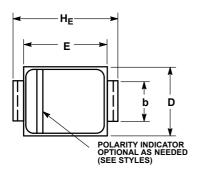


Figure 5. Steady State Power Derating

NSA5.0AT3G

PACKAGE DIMENSIONS

SMA CASE 403D-02 **ISSUE E**





- 1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982. 2. CONTROLLING DIMENSION: INCH.

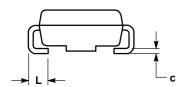
- 3. 403D-01 OBSOLETE, NEW STANDARD IS 403D-02.

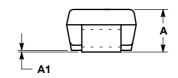
| | М | ILLIMETE | RS | INCHES | | | |
|-----|------|----------|------|--------|-------|-------|--|
| DIM | MIN | NOM | MAX | MIN | NOM | MAX | |
| Α | 1.97 | 2.10 | 2.20 | 0.078 | 0.083 | 0.087 | |
| A1 | 0.05 | 0.10 | 0.15 | 0.002 | 0.004 | 0.006 | |
| b | 1.27 | 1.45 | 1.63 | 0.050 | 0.057 | 0.064 | |
| С | 0.15 | 0.28 | 0.41 | 0.006 | 0.011 | 0.016 | |
| D | 2.29 | 2.60 | 2.92 | 0.090 | 0.103 | 0.115 | |
| E | 4.06 | 4.32 | 4.57 | 0.160 | 0.170 | 0.180 | |
| HE | 4.83 | 5.21 | 5.59 | 0.190 | 0.205 | 0.220 | |
| L | 0.76 | 1.14 | 1.52 | 0.030 | 0.045 | 0.060 | |



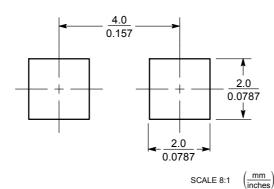
STYLE 1: PIN 1. CATHODE (POLARITY BAND)







SOLDERING FOOTPRINT



Littelfuse products are not designed for, and shall not be used for, any purpose (including, without limitation, automotive, military, aerospace, medical, life-saving, life-sustaining or nuclear facility applications, devices intended for surgical implant into the body, or any other application in which the failure or lack of desired operation of the product may result in personal injury, death, or property damage) other than those expressly set forth in applicable Littelfuse product documentation. Warranties granted by Littelfuse shall be deemed void for products used for any purpose not expressly set forth in applicable Littelfuse documentation. Littelfuse shall not be liable for any claims or damages arising out of products used in applications not expressly intended by Littelfuse as set forth in applicable Littelfuse documentation. The sale and use of Littelfuse products is subject to Littelfuse Terms and Conditions of Sale, unless otherwise agreed by Littelfuse.

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P6KE39CA-TP P6KE8.2A SA110CA SA60CA SA64CA SMBJ12CATR SMBJ8.0A SMLJ30CA-TP ESD112-B1-02EL E6327
ESD119B1W01005E6327XTSA1 ESD5V0J4-TP ESD5V0L1B02VH6327XTSA1 ESD7451N2T5G 19180-510 CPDT-5V0USP-HF
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VESD12A1A-HD1-GS08 CPDUR5V0R-HF CPDUR24V-HF CPDQC5V0U-HF CPDQC5V0USP-HF CPDQC5V0-HF D1213A-01LP4-7B
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